

Density-controlled carbon nanotubes

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Abstract

We demonstrate that the field emission efficiency was greatly improved by reducing the density of carbon nanotubes (CNTs). In this study, catalyst composed of gold and nickel was deposited by e-gun evaporation before pre-treatment of furnace annealing. Carbon nanotubes were then grown on silicon substrate using bias-assisted microwave plasma chemical vapor deposition. Vertical aligned carbon nanotubes were grown with gas mixture of methane and hydrogen under external DC bias. The surface morphology and the tubular structure of carbon nanotubes were confirmed by electron microscopy and the density of carbon nanotubes could be controlled by the composition of the catalyst. The field emission properties were investigated through I – V measurement and the effects are discussed.

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1. Introduction

Carbon nanotubes have drawn a lot of attentions in decade due to their amazing physical and chemical properties as mechanical strength [1], heat conductance [2,3], aspect ratio, surface area and chemical stability. These superior abilities make CNT a good candidate for applications, for example, field effect transistors [4], Bio-Nanotube Membranes [5], fuel cells [6], and field emission devices [7]. Particularly, due to the advantages of high aspect ratio and electrical conductivity, relative low turn-on field, stable emission and life time can therefore be obtained for optimizing the performance of the field emission devices. Carbon nanotubes uses as field emitters have extensively been studied for years and probably to be the first commercial products [8] ever since their discovery.

It has been reported that the maximum current density of 10^9 A/cm² [9] can be transmitted by a CNT with contact electrodes and field emission from a single multi-walled CNTs reaches about 0.2 mA [10] which correspond to a current density of about 10^5 A/cm². These current densities

were far beyond the requirement for practical field emission applications [11] and were hard to accomplish. Efforts have been made to improve the filed emission efficiency of CNTs, which includes purification [12] or doping [13], but the most effective ways are decreasing the density of the CNTs [14–16]. Methods like screen printing, anodic aluminium oxide (AAO) [17] and plasma etching [18,19] were used to adjust the field emission behaviour while complicated procedures generates more problems. It has been reported that the density of CNTs plays a significant role in the field emission behaviours, and theoretical value of the optimal CNTs' density was calculated as 2.5×10^7 emitters/cm² [15]. The screening effect varies with the CNTs' density drastically and the field enhancement is changed. In this study, CNTs' density can be tuned by varying the catalyst's composition or size and the density effect is confirmed experimentally. By directly changing the catalyst composition, it is possible to simplify the field emission devices processes.

2. Experimental details

Mirror-polished n-type, (100) oriented Si wafers with resistivity of 4.5–5.5 Ω /cm were cleaned by standard cleaning process to remove contaminations. Wet oxidation

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was then carried out using a high-temperature furnace system (model ASM LB-45) to form a layer of SiO_2 with thickness of 300 Å in order to prevent silicide formation between silicon and nickel. After that, nickel and gold film with total thickness of 200 Å was deposited sequentially on SiO_2 using an E-Gun Evaporator (model ULVAC EBX-10C, Japan). The specimen was then introduced into a programmable furnace and anneals at a temperature of 900 °C and kept for 2 h under argon atmosphere and then cooled to room temperature.

The pre-treated substrates underwent bias-assisted microwave plasma chemical vapor deposition to grow the CNTs. The microwave power was maintained at 400 W with an external negative DC voltage supplied to the substrate. The total pressure in the chamber was kept at 2000 Pa with reactive gas of a mixture with $\text{H}_2/\text{CH}_4=40:10$ introduced into the quartz chamber. The synthesis temperature was about 700 °C, as measured with an IR thermometer (Minolta TR-630).

After deposition, the CNTs were characterized by scanning electron microscope (SEM; JEOL JSM-6500F) with an acceleration voltage of 15 kV to observe the surface morphology. High resolution transmission electron microscopy (HR-TEM; Philips Tecnai 20) operating at

200 kV and Energy-Dispersive Spectrometry (EDS) was used to observe the nanostructure and the composition of the CNTs. The I – V measurement was taken at a pressure of 10^{-4} Pa with an indium–tin–oxide (ITO) glass as anode.

3. Results and discussion

It was shown in Fig. 1 that the surface roughness increased and the catalyst film tends to form spherical particles as the composition of gold increases due to relief of surface energy after furnace annealing. The catalyst particles gradually increased their size from flat surface to hundreds of nanometers in diameter. The increasing gold content leads to the decreasing nickel–gold alloy melting point and thus the particle sizes were increased. It can be seen from the Ni–Au phase diagram that nickel and gold tend to dissolve to each other easily, which means that the catalyst particle contains both nickel and gold. Although nickel and gold completely dissolve to each other at 900 °C and spinodal decomposition area exists, insufficient cooling rate contributing to nickel-rich and gold-rich domains exists which is the main idea of

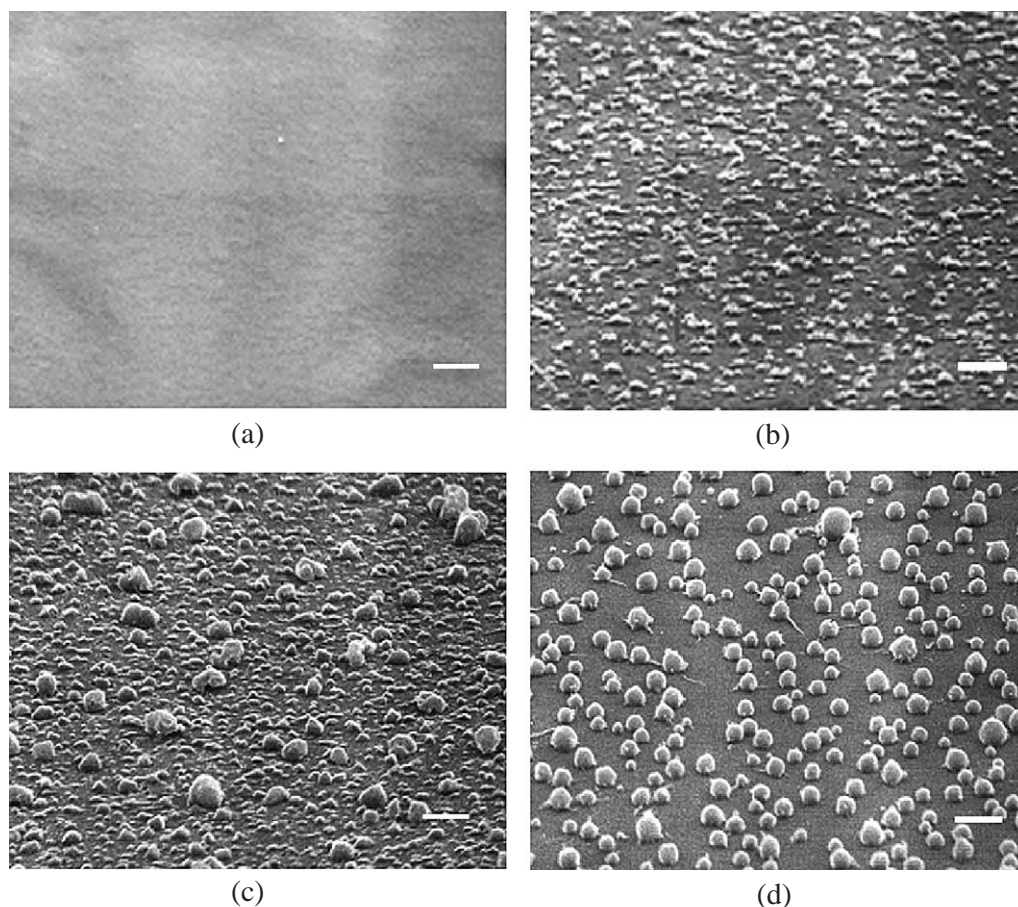


Fig. 1. Surface morphologies with different film composition of (a) Ni 170 Å, Au 30 Å (b) Ni 150 Å, Au 50 Å (c) Ni 130 Å, Au 70 Å (d) Ni 100 Å, Au 100 Å, which show different surface roughness. The scale bar in the image is 1 μm.

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